

Stereo Headphone Amplifier With Shutdown Mode

### Features

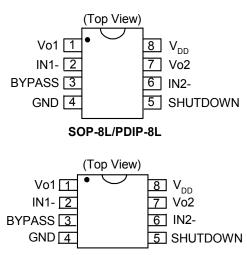
- Operate from 3V to 7V Single Supply Voltage
- High Signal-to-Noise ratio
- High Slew Rate
- Large Output Voltage Swing
- Low Distortion
- Low Power Consumption
- Switch On/Off Click suppression
- Excellent Power Supply Ripple Rejection
- SOP-8, PDIP-8 and MSOP-8 Pb-Free Packages

## Applications

- CD-ROM, DVD-ROM
- MP3 Player
- Battery Powered Devices

Pin Assignments

- Personal Computers



#### MSOP-8L

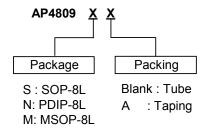
# General Description

The AP4809 is a stereo power amplifier in an 8-pin SOP package capable of delivering 70mW continuous average power per channel into  $32\Omega$  loads with less than 0.1% (THD+N) from a 5V power supply. Amplifier gain is externally configured by means of two resistors per input channel. It was designed specially to provide high quality output power with a minimal amount of external components and is therefore optimally suited for low-power portable systems.

# Pin Descriptions

Pin No.	Pin Name	Description				
1	Vo1	Output 1				
2	IN1-	Inverting input 1				
3	BYPASS	Tap to voltage divider for internal mid-rail bias supply.				
4	GND	Ground				
5	SHUTDOWN	Logic low to put chip in shutdown mode.				
6	IN2-	Inverting input 2				
7	Vo2	Output 2				
8	V <sub>DD</sub>	Positive power supply				

## Ordering Information



This datasheet contains new product information. Anachip Corp. reserves the rights to modify the product specification without notice. No liability is assumed as a result of the use of this product. No rights under any patent accompany the sale of the product.



## ■ Absolute Maximum Ratings (T<sub>A</sub>=25°C)

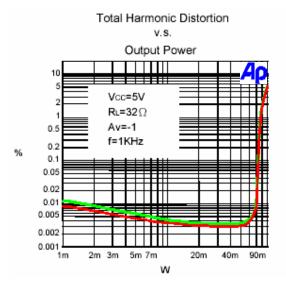
Symbol	Parameter	Max.	Unit
V <sub>DD</sub>	Supply Voltage	7	V
TJ	Junction Temperature	150	°C
Ts	Soldering Temperature, 10 Seconds	250	°C
T <sub>A</sub>	Operating Ambient Temperature Range	-40 to 85	°C
T <sub>STG</sub>	Storage Temperature Range	-65 to 150	°C
V <sub>ESD</sub>	ESD Susceptibility (Note 1)	2000	V
P <sub>D</sub>	Package Power Dissipation	500	mW

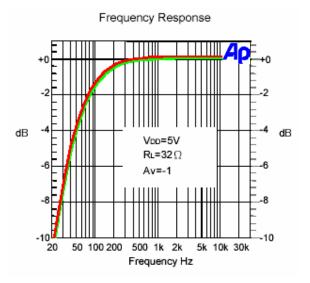
Note 1: Human Body Model, C=100pF, R=1500Ω, 3 positive pulses and 3 Negative Pulses.

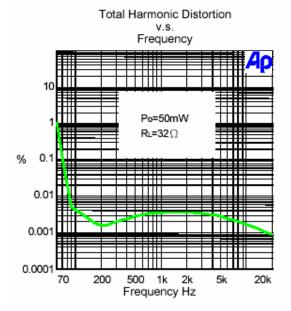
## ■ Electrical Characteristics (T<sub>A</sub>=25°C, V<sub>DD</sub>=5V, f<sub>i</sub>=1KHz, R<sub>L</sub>=32Ω)

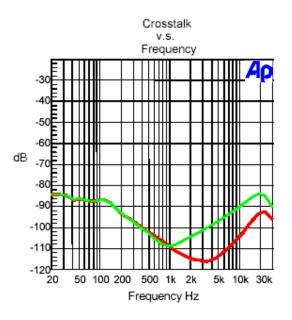
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
V <sub>DD</sub>	Supply Voltage		2.5	-	5.5	V
I <sub>DD</sub>	Supply Current	V <sub>IN</sub> =0V, I <sub>O</sub> =0A	-	3	5	mA
P <sub>TOT</sub>	Total Power Dissipation V <sub>IN</sub> =0V, I <sub>O</sub> =0A		-	10	20	mW
V <sub>I(OS)</sub>	Input Offset Voltage	V <sub>IN</sub> =0V	-	5	-	mV
I <sub>BIAS</sub>	Input Bias Current		-	10	-	pА
$V_{CM}$	Common Mode Voltage		0	-	3.5	V
Gv	Open-Loop Voltage Gain	R <sub>L</sub> =5KΩ	-	80	-	dB
Ιo	Max. Output Current	THD+N < 0.1%	-	80	-	mA
V <sub>SHUT</sub>	Shutdown Enabled	Shutdown Pin Voltage	-	-	0.7	V
V <sub>SHUT</sub>	Shutdown Disabled	Shutdown Pin Voltage	0.9	-	-	V
Ro	Output Resistance		-	0.3	-	Ω
V		R <sub>L</sub> =16Ω, THD+N=0.1%	0.24	-	4.43	V
Vo	Output Voltage Swing	R <sub>L</sub> =32Ω, THD+N=0.1%	0.12	-	4.69	V
PSRR	Power Supply Ripple Rejection		-	75	-	dB
$\alpha_{\rm S}$	Channel Separation	R <sub>L</sub> =32Ω	-	80	-	dB
THD+N	Total Harmonic Distortion + Noise	R <sub>L</sub> =32Ω V <sub>O</sub> =3.2V <sub>P-P</sub> (at 0 dB)	-	0.02	-	%
SNR	Signal-TO-Noise Ratio	V <sub>O</sub> =3.2V <sub>P-P</sub> (at 0 dB)	-	105	-	dB
$f_{G}$	Unity Gain Frequency	Open Loop, R <sub>L</sub> =5KΩ	-	6	-	MHz
Po	Output Power	R <sub>L</sub> =32Ω, THD+N=0.1%	-	75	-	mW
SR	Slew Rate	Unity Gain Inverting	-	6	-	V/µs

# Typical Performance Characteristics



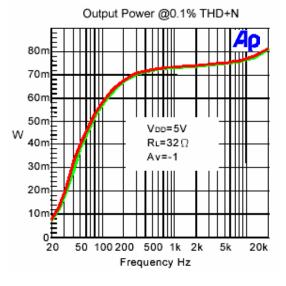




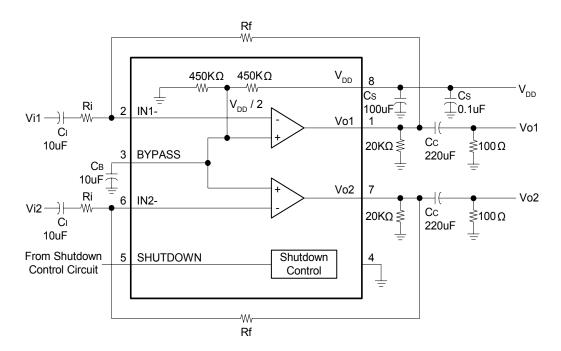


**Typical Performance Characteristics** 

#### Signal to Noise Ratio -01 Ao -85 -90 -95 dB -100 -105 -110 -115 -120<sup>±</sup> 50 100 200 500 1k 2k Frequency Hz 20 2k 5k 20k



# Test Circuit



Stereo Headphone Amplifier With Shutdown Mode

## Application Information

#### 1. Input Capacitor, C<sub>1</sub>

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In the typical application, an input capacitor,  $C_i$ , is required to allow the amplifier to bias the input signal to the proper dc level for optimum operation. In this case,  $C_i$  and  $R_i$  form a high-pass filter with the corner frequency determined in following equation (1).

$$f_{co(highpass)} = \frac{1}{2\pi R_i C_i}$$
(1)

The value of  $C_i$  is important to consider, as it directly affects the low frequency performance of the circuit. Consider the example where  $R_i$  is  $15k\Omega$  and the specification calls for a flat bass response down to 20Hz. Equation (1) is reconfigured as below:

$$C_i = \frac{1}{2\pi R_i f_{co(highpass)}} (2)$$

In this example,  $C_i$  is 0.5  $\mu$ F, so one would likely choose a value in the range of 1µF to 2.2µF. A further consideration for this capacitor is the leakage path from the input source through the input network (R<sub>i</sub>, C<sub>i</sub>) and the feedback resistor (R<sub>f</sub>) to the load. This leakage current creates a dc offset voltage at the input to the amplifier that reduces useful headroom, especially in high-gain applications (>10). For this reason a low-leakage tantalum or ceramic capacitor is the best choice. When polarized capacitors are used, the positive side of the capacitor should face the amplifier input in most applications, as the dc level there is held at  $V_{DD}/2$ , which is likely higher than the source dc level. It is important to confirm the capacitor polarity in the application.

#### 2. Power Supply Decoupling, Cs

The AP4809 is a high-performance CMOS audio amplifier that requires adequate power supply decoupling to ensure that the output total harmonic distortion (THD) is as low as possible. Power supply decoupling also prevents oscillations for long lead lengths between the amplifier and the speaker. The optimum decoupling is achieved by using two capacitors of different types that target different types of noise on the power supply leads. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent-series-resistance (ESR) ceramic capacitor, typically 0.1µF, placed as close as possible to the device  $V_{\text{DD}}$  lead, works best. For filtering lower-frequency noise signals, a larger aluminum electrolytic capacitor of 10µF or greater placed near the power amplifier is recommended.

#### 3. Mid-rail Bypass Capacitor, C<sub>B</sub>

In the consideration of reducing the start-up pop, the mid-rail voltage should rise at a sub-sonic rate; that is, less than the rise time of 20Hz waveform and slower than the charging rate of both  $C_i \& C_C$ . The relationship shown in equation (3) should be maintained to keep the noise as low as possible. Where  $C_B$  is the value of bypass capacitor and  $R_{SOURCE}$  is the equivalent source impedance of the voltage divider (the parallel combination of the two resistors)

$$\frac{1}{C_{B} \times R_{SOURCE}} \leq \frac{1}{C_{i}R_{i}} < < \frac{1}{R_{L}R_{C}}$$
(3)

The bypass capacitor,  $C_B$ , serves several important functions. During start-up,  $C_B$  determines the rate at which the amplifier starts up. This helps to push the start-up pop noise into the sub-audible range (so slow it can not be heard). The second function is to reduce noise produced by the power supply caused by coupling into the output drive signal. This noise is from the mid-rail generation circuit internal to the amplifier. The capacitor is fed from the resistor divider with equivalent resistance of  $R_{SOURCE}$ . On selection of bypass capacitor,  $C_B$ , ceramic or tantalum low-ESR capacitors are recommended for the best THD and noise performance.

#### 4. Output Coupling Capacitor, Cc

In the typical single-supply single-ended (SE) configuration, an output coupling capacitor ( $C_c$ ) is required to block the dc bias at the output of the amplifier, thus preventing dc currents in the load. As with the input coupling capacitor, the output coupling capacitor and impedance of the load form a high-pass filter governed by equation (4).

$$f_{(\text{out high})} = \frac{1}{2\pi R_L C_C}$$
(4)

The main disadvantage, from a performance standpoint, is that the typically small load impedances drive the low-frequency corner higher. Large values of  $C_C$  are required to pass low frequencies into the load.

The output coupling capacitor required in single-supply SE mode also places additional constraints on the selection of other components in the amplifier circuit. With the rules described earlier still valid, add the following relationship:



Stereo Headphone Amplifier With Shutdown Mode

## Application Information (Continued)

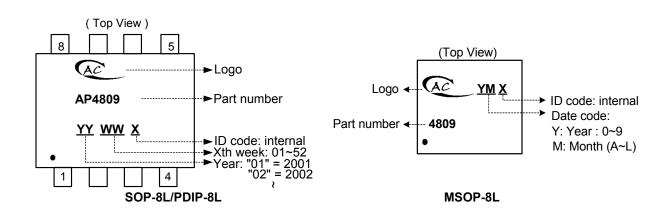
#### 4.1 Output Pull-Down Resistor, R<sub>c</sub> + R<sub>o</sub>

Marking Information

Placing a 100 $\Omega$  resistor, R<sub>c</sub>, from the output side of the coupling capacitor to ground insures the coupling capacitor, C<sub>c</sub>, is charged before a plug is inserted into the jack. Without this resistor, the coupling capacitor would charge rapidly upon insertion of a plug, leading to an audible pop in the headphones. Placing a 20k $\Omega$  resistor, R<sub>o</sub>, from the output of the IC to ground insures that the coupling capacitor fully discharges at power down. If the supply is rapidly cycled without this capacitor, a small pop may be audible in 10k $\Omega$  loads.

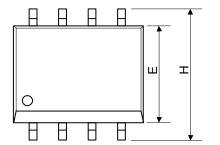
#### 4.2 Using Low-ESR Capacitors

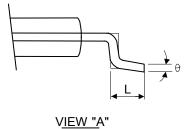
Low-ESR capacitors are recommended throughout this application. A real capacitor can be modeled simply as a resistor in series with an ideal capacitor. The voltage drop across this resistor minimizes the beneficial effects of the capacitor in the circuit. The lower the equivalent value of this resistance, the more the real capacitor behaves like an ideal capacitor.

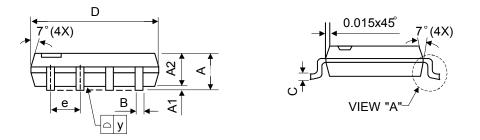


# Package Information

(1) Package Type: SOP-8L







Symbol	Dimensions In Millimeters			Dimensions In Inches		
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.
Α	1.40	1.60	1.75	0.055	0.063	0.069
A1	0.10	-	0.25	0.040	-	0.100
A2	1.30	1.45	1.50	0.051	0.057	0.059
В	0.33	0.41	0.51	0.013	0.016	0.020
С	0.19	0.20	0.25	0.0075	0.008	0.010
D	4.80	5.05	5.30	0.189	0.199	0.209
E	3.70	3.90	4.10	0.146	0.154	0.161
е	-	1.27	-	-	0.050	-
Н	5.79	5.99	6.20	0.228	0.236	0.244
L	0.38	0.71	1.27	0.015	0.028	0.050
у	-	-	0.10	-	-	0.004
θ	0 <sup>0</sup>	-	8 <sup>0</sup>	0 <sup>0</sup>	-	8 <sup>0</sup>

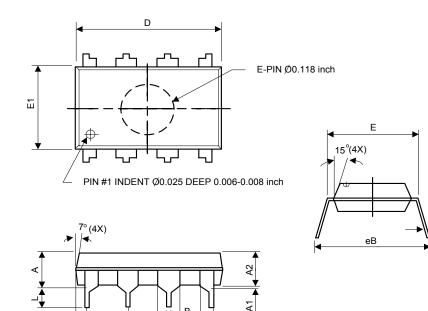
С

# Package Information(Continued)

(2) Package Type: PDIP-8L

S

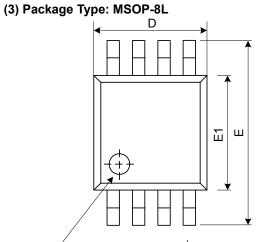
е



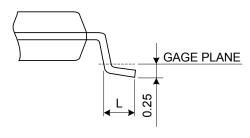
B2

Symbol	Dimensions in millimeters			Dimensions in inches		
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.
А	-	-	5.33	-	-	0.210
A1	0.38	-	-	0.015	-	-
A2	3.1	3.30	3.5	0.122	0.130	0.138
В	0.36	0.46	0.56	0.014	0.018	0.022
B1	1.4	1.52	1.65	0.055	0.060	0.065
B2	0.81	0.99	1.14	0.032	0.039	0.045
С	0.20	0.25	0.36	0.008	0.010	0.014
D	9.02	9.27	9.53	0.355	0.365	0.375
E	7.62	7.94	8.26	0.300	0.313	0.325
E1	6.15	6.35	6.55	0.242	0.250	0.258
е	-	2.54	-	-	0.100	-
L	2.92	3.3	3.81	0.115	0.130	0.150
eB	8.38	8.89	9.40	0.330	0.350	0.370
S	0.71	0.84	0.97	0.028	0.033	0.038

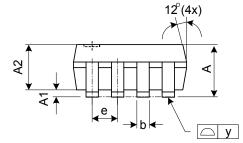
# Package Information (Continued)

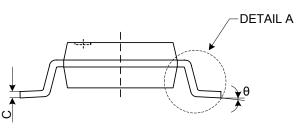


✓ PIN 1 INDICATOR Ø 0.45 mm × 0.038DP SURFACE POLISHED









Symbol	Dimensions In Millimeters			Dimensions In Inches		
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.
Α	0.81	1.02	1.22	0.032	0.040	0.048
A1	0.05	-	0.15	0.002	-	0.006
A2	0.76	0.86	0.97	0.030	0.034	0.038
b	0.28	0.30	0.38	0.011	0.012	0.015
С	0.13	0.15	0.23	0.005	0.006	0.009
D	2.90	3.00	3.10	0.114	0.118	0.122
E	4.80	4.90	5.00	0.189	0.193	0.197
E1	2.90	3.00	3.10	0.114	0.118	0.122
е	-	0.65	-	-	0.0256	-
L	0.40	0.53	0.66	0.016	0.021	0.026
у	-	-	0.076	-	-	0.003
θ	0°	3°	6°	0°	3°	6°